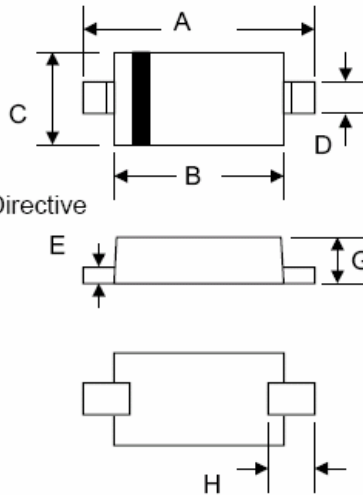




**Technical Data**  
**Data Sheet N0572, Rev. -**  
**Features**

- High Conductance
- Fast Switching Speed
- Surface Mount Package Ideally Suited for Automatic Insertion
- For General Purpose Switching Application
- Plastic Material – UL Recognition Flammability Classification 94V-0
- Green Products in Compliance with the RoHS Directive
- This is a Pb - Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



| SOD-323 |       |      |         |       |
|---------|-------|------|---------|-------|
| Dim     | Min   | Max  | Min     | Max   |
| A       | 2.30  | 2.70 | 0.091   | 0.106 |
| B       | 1.75  | 1.95 | 0.069   | 0.077 |
| C       | 1.15  | 1.35 | 0.045   | 0.053 |
| D       | 0.25  | 0.35 | 0.010   | 0.014 |
| E       | 0.05  | 0.15 | 0.002   | 0.006 |
| G       | 0.70  | 0.95 | 0.028   | 0.037 |
| H       | 0.30  | —    | 0.012   | —     |
|         | In mm |      | In inch |       |

**Mechanical Data**

- Case: SOD-323, Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 0.004 grams (approx.)
- Marking: A2

**Maximum Ratings** @T<sub>A</sub>=25°C unless otherwise specified

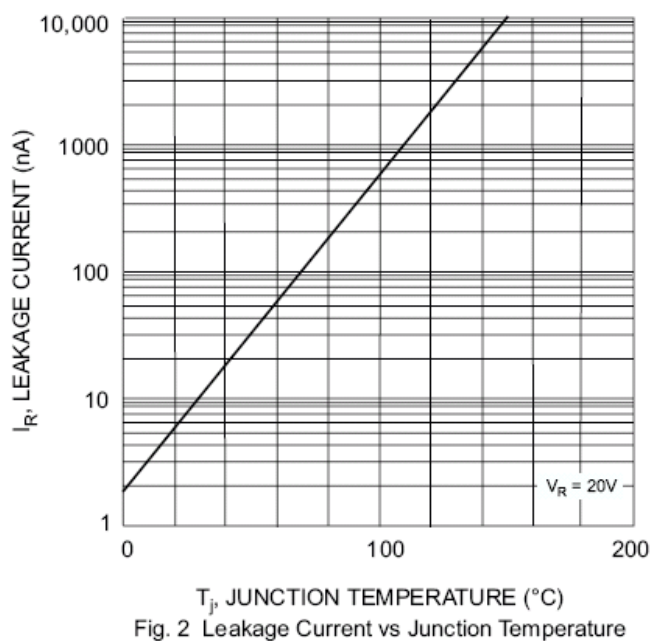
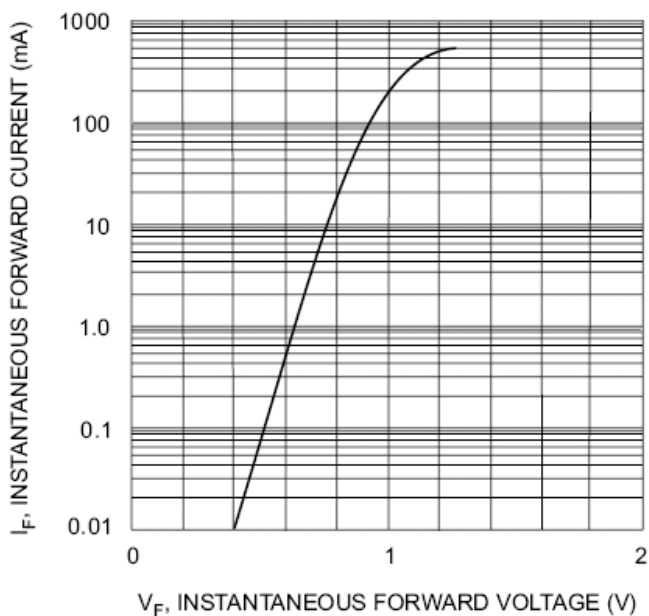
| Characteristic   | Symbol   | 1N4148WS    | Unit |
|--|--|-------------|------|
| Non-Repetitive Peak Reverse Voltage  | V <sub>RM</sub>  | 100         | V    |
| Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage | V <sub>RRM</sub><br>V <sub>RWM</sub><br>V <sub>R</sub> | 75          | V    |
| RMS Reverse Voltage  | V <sub>R(RMS)</sub>                                    | 53          | V    |
| Forward Continuous Current (Note 1)  | I <sub>FM</sub>  | 300         | mA   |
| Average Rectified Output Current (Note 1)  | I <sub>o</sub>   | 150         | mA   |
| Non-Repetitive Peak Forward Surge Current  | I <sub>FSM</sub>                                       | 2.0<br>1.0  | A    |
|  | @ t = 1.0µs<br>@ t = 1.0s                              |             |      |
| Power Dissipation (Note 1)   | P <sub>d</sub>   | 200         | mW   |
| Typical Thermal Resistance, Junction to Ambient Air (Note 1)                           | R <sub>θJA</sub>                                       | 625         | K/W  |
| Operating and Storage Temperature Range  | T <sub>J</sub> , T <sub>STG</sub>                      | -65 to +150 | °C   |



**Electrical Characteristics** @ $T_A=25^{\circ}\text{C}$  unless otherwise specified

| Characteristic  | Symbol   | 1N4148WS | Unit          |
|---|----------|----------|---------------|
| Forward Voltage Drop @ $I_F = 10\text{mA}$                          | $V_{FM}$ | 1.0      | V             |
| Peak Reverse Leakage Current @ $V_R = 75\text{V}$                   | $I_{RM}$ | 2.5      | $\mu\text{A}$ |
| Junction Capacitance ( $V_R = 0\text{V DC}$ , $f = 1.0\text{MHz}$ ) | $C_j$    | 2.0      | pF            |
| Reverse Recovery Time (Note 2)                                      | $t_{rr}$ | 4.0      | nS            |

Note: 1. Valid provided that terminals are kept at ambient temperature.  
2. Measured with  $I_F = I_R = 10\text{mA}$ ,  $I_{RR} = 0.1 \times I_R$ ,  $R_L = 100\ \Omega$ .





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